

# Low Noise, Low Drift Single-Supply Operational Amplifiers 0P113/0P213/0P413

#### FEATURES

Single- or dual-supply operation Low noise: 4.7 nV/√Hz @ 1 kHz Wide bandwidth: 3.4 MHz Low offset voltage: 100 µV Very low drift: 0.2 µV/°C Unity gain stable No phase reversal

#### **APPLICATIONS**

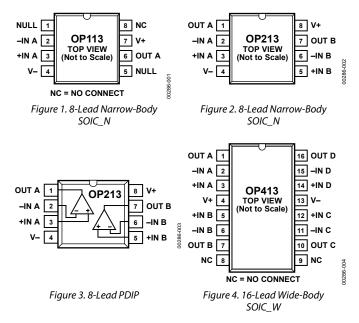
Digital scales Multimedia Strain gages Battery-powered instrumentation Temperature transducer amplifier

#### **GENERAL DESCRIPTION**

The OPx13 family of single-supply operational amplifiers features both low noise and drift. It has been designed for systems with internal calibration. Often these processor-based systems are capable of calibrating corrections for offset and gain, but they cannot correct for temperature drifts and noise. Optimized for these parameters, the OPx13 family can be used to take advantage of superior analog performance combined with digital correction. Many systems using internal calibration operate from unipolar supplies, usually either 5 V or 12 V. The OPx13 family is designed to operate from single supplies from 4 V to 36 V and to maintain its low noise and precision performance.

The OPx13 family is unity gain stable and has a typical gain bandwidth product of 3.4 MHz. Slew rate is in excess of 1 V/µs. Noise density is a very low 4.7 nV/ $\sqrt{Hz}$ , and noise in the 0.1 Hz to 10 Hz band is 120 nV p-p. Input offset voltage is guaranteed and offset drift is guaranteed to be less than 0.8  $\mu$ V/°C. Input common-mode range includes the negative supply and to within 1 V of the positive supply over the full supply range. Phase reversal protection is designed into the OPx13 family for cases where input voltage range is exceeded. Output voltage swings also include the negative supply and go to within 1 V of the positive range is capable of sinking and sourcing current throughout its range and is specified with 600  $\Omega$  loads.

### **PIN CONFIGURATIONS**



Digital scales and other strain gage applications benefit from the very low noise and low drift of the OPx13 family. Other applications include use as a buffer or amplifier for both analogto-digital (ADC) and digital-to-analog (DAC) sigma-delta converters. Often these converters have high resolutions requiring the lowest noise amplifier to utilize their full potential. Many of these converters operate in either singlesupply or low-supply voltage systems, and attaining the greater signal swing possible increases system performance.

The OPx13 family is specified for single 5 V and dual  $\pm$ 15 V operation over the XIND—extended industrial temperature range (-40°C to +85°C). They are available in PDIP and SOIC surface-mount packages.

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### **SPECIFICATIONS**

### **ELECTRICAL CHARACTERISTICS**

@  $\rm V_{S}$  = ±15.0 V,  $\rm T_{A}$  = 25°C, unless otherwise noted.

### Table 1.

|                                       | E Grade                  |   | e    | F Grade |       |      |     |       |       |
|---------------------------------------|--------------------------|---|------|---------|-------|------|-----|-------|-------|
| Parameter                             | Symbol                   | Conditions  | Min  | Тур     | Max   | Min  | Тур | Max   | Unit  |
| INPUT CHARACTERISTICS                 |                          |   |      |         |       |      |     |       |       |
| Offset Voltage                        | Vos                      | OP113   |      |         | 75    |      |     | 150   | μV    |
|                                       |                          | $-40^\circ C \le T_A \le +85^\circ C$                       |      |         | 125   |      |     | 225   | μV    |
|                                       |                          | OP213   |      |         | 100   |      |     | 250   | μV    |
|                                       |                          | $-40^\circ C \le T_A \le +85^\circ C$                       |      |         | 150   |      |     | 325   | μV    |
|                                       |                          | OP413   |      |         | 125   |      |     | 275   | μV    |
|                                       |                          | $-40^\circ C \leq T_A \leq +85^\circ C$                     |      |         | 175   |      |     | 350   | μV    |
| Input Bias Current                    | IB                       | $V_{CM} = 0 V$  |      | 240     | 600   |      |     | 600   | nA    |
|                                       |                          | $-40^\circ C \le T_A \le +85^\circ C$                       |      |         | 700   |      |     | 700   | nA    |
| Input Offset Current                  | los                      | $V_{CM} = 0 V$  |      |         |       |      |     |       |       |
|                                       |                          | $-40^\circ C \le T_A \le +85^\circ C$                       |      |         | 50    |      |     | 50    | nA    |
| Input Voltage Range                   | Vcm                      |   | -15  |         | +14   | -15  |     | +14   | V     |
| Common-Mode Rejection                 | CMR                      | $-15~V \leq V_{CM} \leq +14~V$                              | 100  | 116     |       | 96   |     |       | dB    |
|                                       |                          | $-15 \text{ V} \le \text{V}_{\text{CM}} \le +14 \text{ V},$ |      |         |       |      |     |       |       |
|                                       |                          | $-40^{\circ}C \le T_A \le +85^{\circ}C$                     | 97   | 116     |       | 94   |     |       | dB    |
| Large-Signal Voltage Gain             | Avo                      | OP113, OP213,   |      |         |       |      |     |       |       |
|                                       |                          | $R_L = 600 \Omega$ ,  |      |         |       |      |     |       |       |
|                                       |                          | $-40^{\circ}C \le T_A \le +85^{\circ}C$                     | 1    | 2.4     |       | 1    |     |       | V/µV  |
|                                       |                          | OP413, $R_L = 1 k\Omega$ ,                                  |      |         |       |      |     |       |       |
|                                       |                          | $-40^{\circ}C \le T_A \le +85^{\circ}C$                     | 1    | 2.4     |       | 1    |     |       | V/µV  |
|                                       |                          | $R_L = 2 k\Omega$ ,   |      |         |       |      |     |       |       |
|                                       |                          | $-40^{\circ}C \le T_A \le +85^{\circ}C$                     | 2    | 8       |       | 2    |     |       | V/µV  |
| Long-Term Offset Voltage <sup>1</sup> | Vos                      |   |      |         | 150   |      |     | 300   | μV    |
| Offset Voltage Drift <sup>2</sup>     | $\Delta V_{os}/\Delta T$ |   |      | 0.2     | 0.8   |      |     | 1.5   | µV/°C |
| OUTPUT CHARACTERISTICS                |                          |   |      |         |       |      |     |       |       |
| Output Voltage Swing High             | Vон                      | $R_L = 2 k\Omega$   | 14   |         |       | 14   |     |       | V     |
|                                       |                          | $R_L = 2 k\Omega$ ,   |      |         |       |      |     |       |       |
|                                       |                          | $-40^{\circ}C \le T_A \le +85^{\circ}C$                     | 13.9 |         |       | 13.9 |     |       | V     |
| Output Voltage Swing Low              | Vol                      | $R_L = 2 k\Omega$   |      |         | -14.5 |      |     | -14.5 | V     |
|                                       |                          | $R_L = 2 k\Omega$ ,   |      |         |       |      |     |       |       |
|                                       |                          | $-40^{\circ}C \le T_A \le +85^{\circ}C$                     |      |         | -14.5 |      |     | -14.5 | V     |
| Short-Circuit Limit                   | Isc                      |   |      | ±40     |       |      | ±40 |       | mA    |
| POWER SUPPLY                          |                          |   |      |         |       |      |     |       |       |
| Power Supply Rejection Ratio          | PSRR                     | $V_s = \pm 2 V \text{ to } \pm 18 V$                        | 103  | 120     |       | 100  |     |       | dB    |
|                                       |                          | $V_S = \pm 2 V$ to $\pm 18 V$                               |      |         |       |      |     |       |       |
|                                       |                          | $-40^{\circ}C \le T_{A} \le +85^{\circ}C$                   | 100  | 120     |       | 97   |     |       | dB    |
| Supply Current/Amplifier              | I <sub>SY</sub>          | $V_{OUT} = 0 V, R_L = \infty,$                              |      |         |       |      |     |       |       |
|                                       |                          | $V_s = \pm 18 V$  |      |         | 3     |      |     | 3     | mA    |
|                                       |                          | $-40^{\circ}C \le T_A \le +85^{\circ}C$                     |      |         | 3.8   |      |     | 3.8   | mA    |
| Supply Voltage Range                  | Vs                       |   | 4    |         | ±18   | 4    |     | ±18   | v     |

|                        |                    | E Grade  |     | •      | F Grade |     |        |     |        |
|------------------------|--------------------|--|-----|--------|---------|-----|--------|-----|--------|
| Parameter              | Symbol             | Conditions   | Min | Тур    | Max     | Min | Тур    | Max | Unit   |
| AUDIO PERFORMANCE      |                    |  |     |        |         |     |        |     |        |
| THD + Noise            |                    | $V_{IN} = 3 V \text{ rms}, R_L = 2 \text{ k}\Omega,$ |     |        |         |     |        |     |        |
|                        |                    | f = 1 kHz  |     | 0.0009 |         |     | 0.0009 |     | %      |
| Voltage Noise Density  | en                 | f = 10 Hz  |     | 9      |         |     | 9      |     | nV/√Hz |
|                        |                    | f = 1 kHz  |     | 4.7    |         |     | 4.7    |     | nV/√Hz |
| Current Noise Density  | İn                 | f = 1 kHz  |     | 0.4    |         |     | 0.4    |     | pA/√Hz |
| Voltage Noise          | e <sub>n</sub> p-p | 0.1 Hz to 10 Hz                                      |     | 120    |         |     | 120    |     | nV p-p |
| DYNAMIC PERFORMANCE    |                    |  |     |        |         |     |        |     |        |
| Slew Rate              | SR                 | $R_L = 2 k\Omega$                                    | 0.8 | 1.2    |         | 0.8 | 1.2    |     | V/µs   |
| Gain Bandwidth Product | GBP                |  |     | 3.4    |         |     | 3.4    |     | MHz    |
| Channel Separation     |                    | V <sub>OUT</sub> = 10 V p-p                          |     |        |         |     |        |     |        |
|                        |                    | $R_L = 2 k\Omega$ , f = 1 kHz                        |     | 105    |         |     | 105    |     | dB     |
| Settling Time          | ts                 | to 0.01%, 0V to 10V step                             |     | 9      |         |     | 9      |     | μs     |

<sup>1</sup> Long-term offset voltage is guaranteed by a 1000 hour life test performed on three independent lots at 125°C, with an LTPD of 1.3. <sup>2</sup> Guaranteed specifications, based on characterization data.

@  $V_s = 5.0$  V,  $T_A = 25$ °C, unless otherwise noted.

#### Table 2.

|                                       |                            |  |     | E Grad | e   |     | F Grad | e   |       |
|---------------------------------------|----------------------------|--|-----|--------|-----|-----|--------|-----|-------|
| Parameter                             | Symbol                     | Conditions   | Min | Тур    | Мах | Min | Тур    | Мах | Unit  |
| INPUT CHARACTERISTICS                 |                            |  |     |        |     |     |        |     |       |
| Offset Voltage                        | Vos                        | OP113  |     |        | 125 |     |        | 175 | μV    |
|                                       |                            | $-40^\circ C \le T_A \le +85^\circ C$              |     |        | 175 |     |        | 250 | μV    |
|                                       |                            | OP213  |     |        | 150 |     |        | 300 | μV    |
|                                       |                            | $-40^\circ C \le T_A \le +85^\circ C$              |     |        | 225 |     |        | 375 | μV    |
|                                       |                            | OP413  |     |        | 175 |     |        | 325 | μV    |
|                                       |                            | $-40^\circ C \le T_A \le +85^\circ C$              |     |        | 250 |     |        | 400 | μV    |
| Input Bias Current                    | IB                         | $V_{CM} = 0 V, V_{OUT} = 2$                        |     | 300    | 650 |     |        | 650 | nA    |
|                                       |                            | $-40^{\circ}C \le T_A \le +85^{\circ}C$            |     |        | 750 |     |        | 750 | nA    |
| Input Offset Current                  | los                        | $V_{CM} = 0 V, V_{OUT} = 2$                        |     |        |     |     |        |     |       |
|                                       |                            | $-40^{\circ}C \le T_A \le +85^{\circ}C$            |     |        | 50  |     |        | 50  | nA    |
| Input Voltage Range                   | Vсм                        |  | 0   |        | 4   |     |        | 4   | V     |
| Common-Mode Rejection                 | CMR                        | $0~V \leq V_{\text{CM}} \leq 4~V$                  | 93  | 106    |     | 90  |        |     | dB    |
|                                       |                            | $0 \text{ V} \leq V_{\text{CM}} \leq 4 \text{ V},$ |     |        |     |     |        |     |       |
|                                       |                            | $-40^{\circ}C \leq T_{A} \leq +85^{\circ}C$        | 90  |        |     | 87  |        |     | dB    |
| Large-Signal Voltage Gain             | Avo                        | OP113, OP213,                                      |     |        |     |     |        |     |       |
|                                       |                            | $R_L = 600 \Omega$ , 2 k $\Omega$ ,                |     |        |     |     |        |     |       |
|                                       |                            | $0.01~V \leq V_{\text{OUT}} \leq 3.9~V$            | 2   |        |     | 2   |        |     | V/μV  |
|                                       |                            | OP413, $R_L = 600$ , 2 k $\Omega$ ,                |     |        |     |     |        |     |       |
|                                       |                            | $0.01~V \leq V_{\text{OUT}} \leq 3.9~V$            | 1   |        |     | 1   |        |     | V/μV  |
| Long-Term Offset Voltage <sup>1</sup> | Vos                        |  |     |        | 200 |     |        | 350 | μV    |
| Offset Voltage Drift <sup>2</sup>     | $\Delta V_{OS} / \Delta T$ |  |     | 0.2    | 1.0 |     |        | 1.5 | μV/°C |

|                           |                 |   | E Grade |       |     | F Grad | e     |     |        |
|---------------------------|-----------------|---|---------|-------|-----|--------|-------|-----|--------|
| Parameter                 | Symbol          | Conditions                                    | Min     | Тур   | Мах | Min    | Тур   | Мах | Unit   |
| OUTPUT CHARACTERISTICS    |                 |   |         |       |     |        |       |     |        |
| Output Voltage Swing High | Vон             | $R_L = 600 \ k\Omega$                         | 4.0     |       |     | 4.0    |       |     | V      |
|                           |                 | $R_L = 100 \text{ k}\Omega$ ,                 |         |       |     |        |       |     |        |
|                           |                 | $-40^\circ C \le T_A \le +85^\circ C$         | 4.1     |       |     | 4.1    |       |     | V      |
|                           |                 | $R_L = 600 \Omega$ ,                          |         |       |     |        |       |     |        |
|                           |                 | $-40^\circ C \le T_A \le +85^\circ C$         | 3.9     |       |     | 3.9    |       |     | V      |
| Output Voltage Swing Low  | Vol             | $R_L = 600 \Omega$ ,                          |         |       |     |        |       |     |        |
|                           |                 | $-40^\circ C \le T_A \le +85^\circ C$         |         |       | 8   |        |       | 8   | mV     |
|                           |                 | $R_L = 100 \ k\Omega$ ,                       |         |       |     |        |       |     |        |
|                           |                 | $-40^\circ C \le T_A \le +85^\circ C$         |         | 8     |     |        | 8     |     | mV     |
| Short-Circuit Limit       | Isc             |   |         | ±30   |     |        | ±30   |     | mA     |
| POWER SUPPLY              |                 |   |         |       |     |        |       |     |        |
| Supply Current            | I <sub>SY</sub> | V <sub>OUT</sub> = 2.0 V, no load             |         | 1.6   | 2.7 |        |       | 2.7 | mA     |
|                           | I <sub>SY</sub> | $-40^\circ C \leq T_A \leq +85^\circ C$       |         |       | 3.0 |        |       | 3.0 | mA     |
| AUDIO PERFORMANCE         |                 |   |         |       |     |        |       |     |        |
| THD + Noise               |                 | $V_{OUT} = 0 \text{ dBu, } f = 1 \text{ kHz}$ |         | 0.001 |     |        | 0.001 |     | %      |
| Voltage Noise Density     | en              | f = 10 Hz                                     |         | 9     |     |        | 9     |     | nV/√Hz |
|                           |                 | f = 1  kHz                                    |         | 4.7   |     |        | 4.7   |     | nV/√Hz |
| Current Noise Density     | İn              | f = 1 kHz                                     |         | 0.45  |     |        | 0.45  |     | pA/√Hz |
| Voltage Noise             | en p-p          | 0.1 Hz to 10 Hz                               |         | 120   |     |        | 120   |     | nV p-p |
| DYNAMIC PERFORMANCE       |                 |   |         |       |     |        |       |     |        |
| Slew Rate                 | SR              | $R_L = 2 k\Omega$                             | 0.6     | 0.9   |     | 0.6    |       |     | V/µs   |
| Gain Bandwidth Product    | GBP             |   |         | 3.5   |     |        | 3.5   |     | MHz    |
| Settling Time             | ts              | to 0.01%, 2 V step                            |         | 5.8   |     |        | 5.8   |     | μs     |

<sup>1</sup> Long-term offset voltage is guaranteed by a 1000 hour life test performed on three independent lots at 125°C, with an LTPD of 1.3. <sup>2</sup> Guaranteed specifications, based on characterization data.

### **ABSOLUTE MAXIMUM RATINGS**

#### Table 3.

| Tuble 51                                   |                 |
|--|-----------------|
| Parameter                                  | Rating          |
| Supply Voltage                             | ±18 V           |
| Input Voltage                              | ±18 V           |
| Differential Input Voltage                 | ±10 V           |
| Output Short-Circuit Duration to GND       | Indefinite      |
| Storage Temperature Range                  | –65°C to +150°C |
| Operating Temperature Range                | –40°C to +85°C  |
| Junction Temperature Range                 | –65°C to +150°C |
| Lead Temperature Range (Soldering, 60 sec) | 300°C           |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### THERMAL RESISTANCE

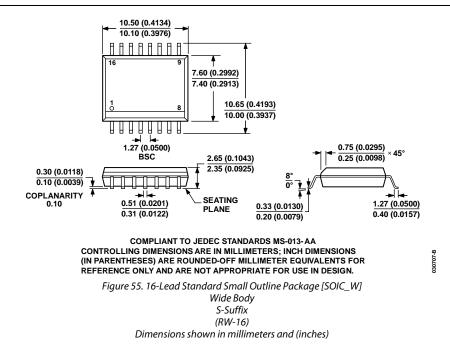
#### Table 4. Thermal Resistance

| Package Type       | Αιθ | θıc | Unit |
|--------------------|-----|-----|------|
| 8-Lead PDIP (P)    | 103 | 43  | °C/W |
| 8-Lead SOIC_N (S)  | 158 | 43  | °C/W |
| 16-Lead SOIC_W (S) | 92  | 27  | °C/W |

### **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.



#### **ORDERING GUIDE**

| Model                       | Temperature Range | Package Description | Package Options |
|-----------------------------|-------------------|---------------------|-----------------|
| OP113ES                     | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP113ES-REEL                | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP113ES-REEL7               | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP113ESZ <sup>1</sup>       | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP113ESZ-REEL <sup>1</sup>  | –40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP113ESZ-REEL7 <sup>1</sup> | –40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP113FS                     | –40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP113FS-REEL                | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP113FS-REEL7               | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP113FSZ <sup>1</sup>       | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP113FSZ-REEL <sup>1</sup>  | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP113FSZ-REEL7 <sup>1</sup> | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP213ES                     | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP213ES-REEL                | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP213ES-REEL7               | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP213ESZ <sup>1</sup>       | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP213ESZ-REEL <sup>1</sup>  | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP213ESZ-REEL71             | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP213FP                     | -40°C to +85°C    | 8-Lead PDIP         | N-8 (P-Suffix)  |
| OP213FPZ <sup>1</sup>       | -40°C to +85°C    | 8-Lead PDIP         | N-8 (P-Suffix)  |
| OP213FS                     | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP213FS-REEL                | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP213FS-REEL7               | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP213FSZ <sup>1</sup>       | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP213FSZ-REEL <sup>1</sup>  | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |
| OP213FSZ-REEL7 <sup>1</sup> | -40°C to +85°C    | 8-Lead SOIC_N       | R-8 (S-Suffix)  |

## OP113/0P213/0P413

| Model                      | Temperature Range | Package Description      | Package Options  |
|----------------------------|-------------------|--------------------------|------------------|
| OP413ES                    | –40°C to +85°C    | 16-Lead Wide Body SOIC_W | RW-16 (S-Suffix) |
| OP413ES-REEL               | –40°C to +85°C    | 16-Lead Wide Body SOIC_W | RW-16 (S-Suffix) |
| OP413ESZ <sup>1</sup>      | –40°C to +85°C    | 16-Lead Wide Body SOIC_W | RW-16 (S-Suffix) |
| OP413ESZ-REEL <sup>1</sup> | –40°C to +85°C    | 16-Lead Wide Body SOIC_W | RW-16 (S-Suffix) |
| OP413FS                    | -40°C to +85°C    | 16-Lead Wide Body SOIC_W | RW-16 (S-Suffix) |
| OP413FS-REEL               | -40°C to +85°C    | 16-Lead Wide Body SOIC_W | RW-16 (S-Suffix) |
| OP413FSZ <sup>1</sup>      | –40°C to +85°C    | 16-Lead Wide Body SOIC_W | RW-16 (S-Suffix) |
| OP413FSZ-REEL <sup>1</sup> | -40°C to +85°C    | 16-Lead Wide Body SOIC_W | RW-16 (S-Suffix) |

 $^{1}$  Z = RoHS Compliant Part.